NSN 5961-01-359-9645

Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-359-9645 **Inclosure Material:** Glass **Overall Length:** 0.200 inches **Overall Diameter:** Between 0.115 inches and 0.180 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 660.0 breakdown voltage, dc **Current Rating Per Characteristic:** 5.00 amperes forward current, average absolute and 100.00 amperes forward current, average preset **Special Features:** Diode mtd in a connector plug **Terminal Type And Quantity:** 2 insulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No